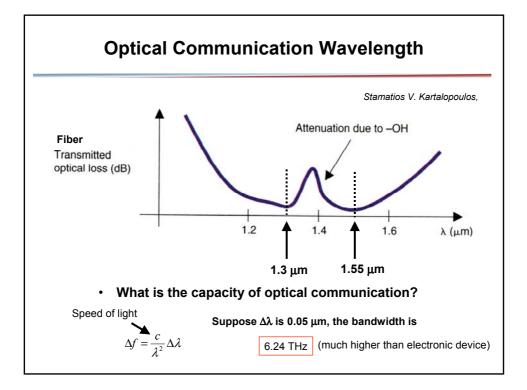


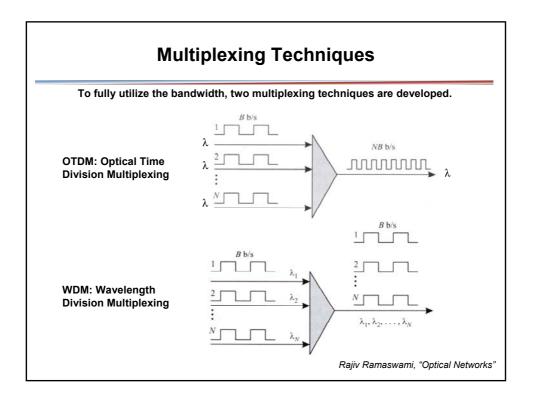
Three Mileage Stones in Developing Optical Communication

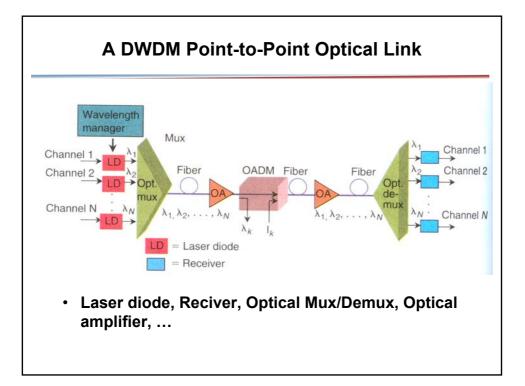
- Laser (optical source) --- 1960s
 - From gas laser to semiconductor laser (diode laser, heterojunction laser,...)
- Low-Loss optical fiber --- 1980s
 1000dB/km → 20dB/km → 0.2dB/km
- Semiconductor manufacturing --- 1990s ~
 - Silicon, III-V, II-VI, silica,...
 - Integrated optical devices

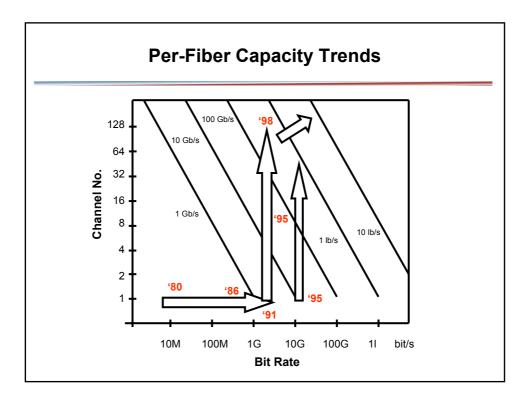


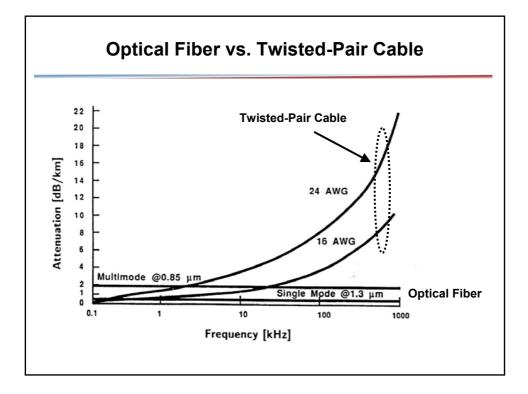
- Immunity from electromagnetic interference (EMI)
- Safety in combustible environments
- Security from monitoring
- Large bandwidth
- Low-loss transmission
- · Small size, light weight
- Inexpensive
- Major disadvantage: difficult to use for electrical power transmission

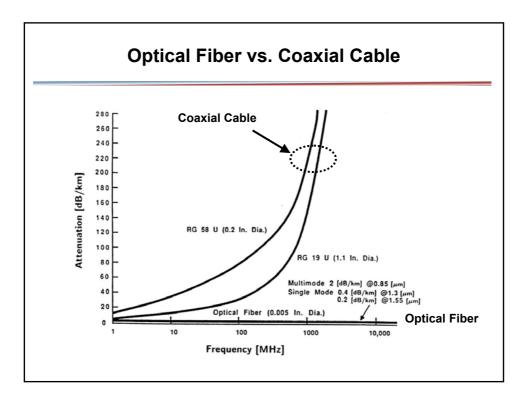


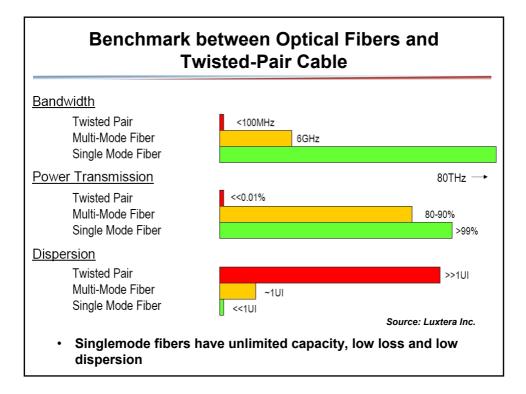


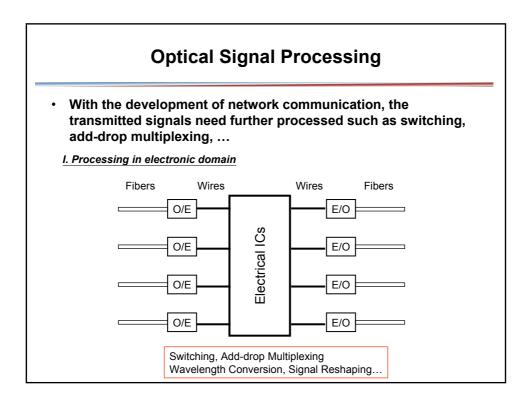


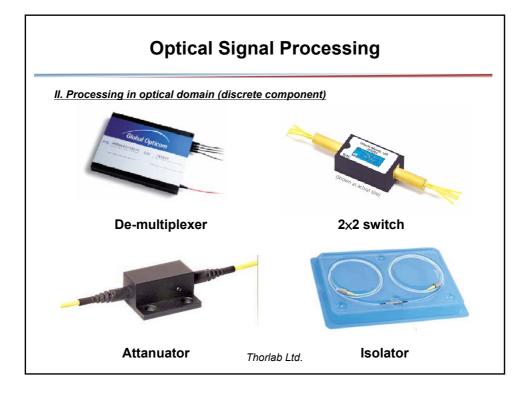


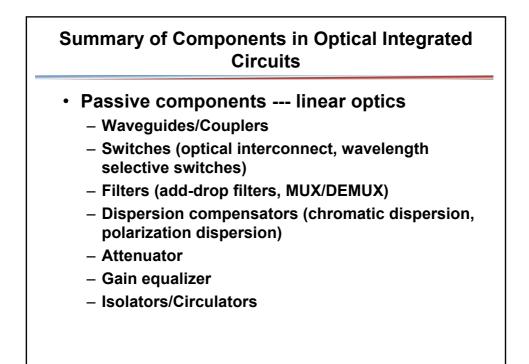






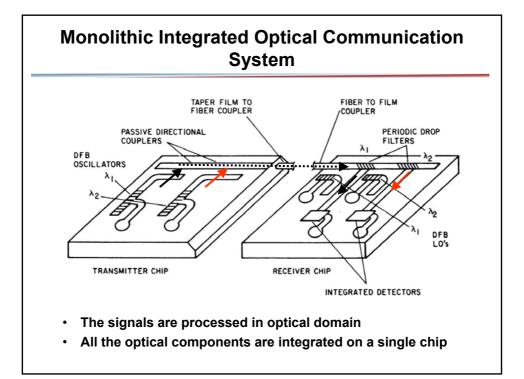


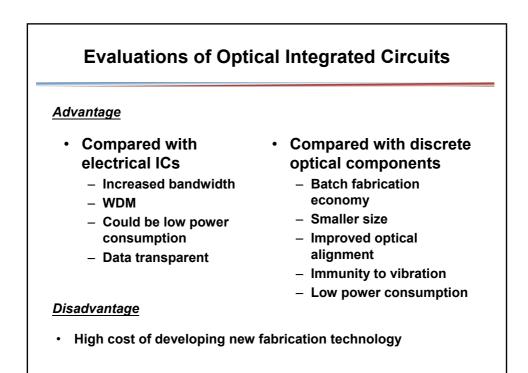


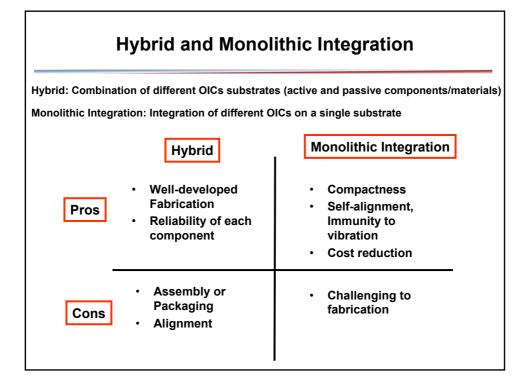


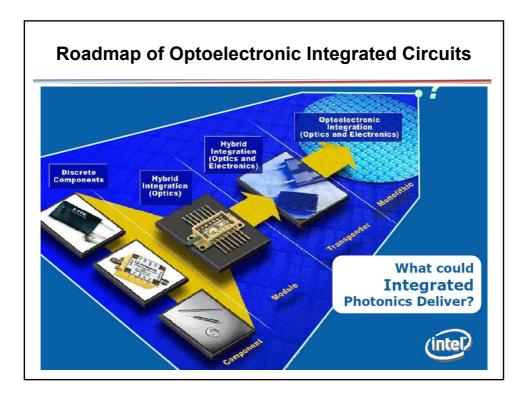
Summary of Components in Optical Integrated Circuits • Active components --- optoelectronics, nonlinear optics - Amplifiers - Lasers - LED • Modulators - Detectors - Wavelength converters

Passive vs. Active	
Passive Materials	Active Materials (light source)
 Quartz (SiO₂) 	 Gallium Arsenide (GaAs)
 Lithium Niobate (LiNbO₃) 	 Gallium Aluminum Arsenide (GaAlAs)
 Lithium Tantalate (LiTaO₃) 	 Gallium Arsenide Phosphide (GaAsP)
Tantalum PentoxideNiobium Pentoxide	 Gallium Indium Arsenide (GalnAs)
SiliconPolymers	 Gallium Indium Arsenide (GalnAs)
	 Other Compound III-V and II-VI









Integrated Photonics: Short-Distance Optical Interconnect

